



Press Release

EpiGaN Awarded National Trends Gazelle Ambassador 'Starter' 2014

Hasselt, Belgium, March 20th, 2014. EpiGaN nv, a leading provider of III-nitride epitaxial materials, was awarded the title of National Trends Gazelle Ambassador 2014 in the category 'Starter' by Trends, a leading financial-economics Belgian magazine. The annual award recognizes EpiGaN for its fast growth in revenue and employees in a three-year time span. It was further selected for its highly innovative products addressing a very large and international market, offering further growth perspective and local job creations. The award was presented to EpiGaN by Flemish Minister President, Mr. Kris Peeters, in Brussels.

"We are thrilled and very proud with this title and recognition," said Marianne Germain, Co-Founder and CEO of EpiGaN. "It is great to be awarded for the hard work of a very committed team and its constant efforts since the founding of the company in 2010. And this is just the beginning, as we are in the middle of expanding our production capacity to support volume growth driven by our worldwide customers."

EpiGaN covers silicon wafers with a layer of Gallium Nitride (GaN). These GaN-on-Si (Gallium Nitride on Silicon) epitaxial wafers are used to make high voltage power transistors and high frequency RF (Radio Frequency) components that helps towards reducing energy losses, increasing the performance and reducing the size of applications such as adaptors for consumer electronics, industrial and server power supplies, AC drives, cellular base stations, cable TV infrastructure, hybrid and electric vehicles, etc.

The company has installed its manufacturing facilities in Hasselt, Belgium, where it found the required clean-room environment. It is ideally located in a very international area in the triangle Aachen, Eindhoven en Leuven. EpiGaN is one of the few Flemish companies that manufacture high tech semiconductor products in Flanders, creating local jobs and contributing to the local economy.

About EpiGaN

EpiGaN has been incorporated in 2010 by Dr. Marianne Germain, CEO, Dr. Joff Derluyn, CTO, and Dr. Stefan Degroote, COO, as a spin-off of imec. In 2011, they were joined in their venture by a strong consortium of investors, formed by Robert Bosch Venture Capital, Capricorn CleanTech Fund and LRM, enabling the installation of a new production facility. It focuses on providing world-leading III-nitride epitaxial

material solutions for top performance devices. EpiGaN offers device manufacturers access to a unique, proven and powerful technology to be used in key market segments such as power supplies for consumables, AC drives, UPS systems, hybrid electric vehicles, solar inverters, smart grid, RF power for base stations, CATV infrastructure, etc. For more information visit www.epigan.com

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